

SM4001...SM4007

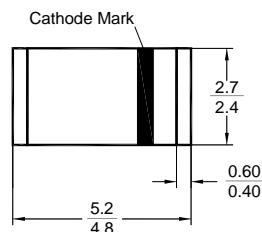
SURFACE MOUNT SILICON RECTIFIERS

Voltage Range - 50 to 1000 V

Forward Current - 1 A

Features

- Low cost
- Ideal for surface mounted applications
- Low leakage current



Mechanical data

- Case: MELF (DO-213AB) molded plastic body
- Mounting position: any

Plastic case MELF (DO-213AB)
Dimensions in mm

Absolute Maximum Ratings and Electrical characteristics ($T_a = 25^\circ\text{C}$)

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbols	SM4001	SM4002	SM4003	SM4004	SM4005	SM4006	SM4007	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current at $T_a = 75^\circ\text{C}$	$I_{F(AV)}$				1				A
Peak Forward Surge Current 8.3 ms Single Half Sine-Wave Superimposed on Rated Load (JEDEC Method)	I_{FSM}				30				A
Maximum Forward Voltage at 1 A	V_F				1.1				V
Maximum Full Load Reverse Current (Full Cycle Average)	$I_{R(AV)}$				30				μA
Maximum DC Reverse Current $T_a = 25^\circ\text{C}$ at Rated DC Blocking Voltage $T_a = 125^\circ\text{C}$	I_R				5 50				μA
Typical Junction Capacitance ¹⁾	C_J				15				pF
Maximum Thermal Resistance	$R_{\theta JL}$ ²⁾ $R_{\theta JA}$ ³⁾				20 50				$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_j, T_{stg}				- 65 to + 150				$^\circ\text{C}$

¹⁾ Measured at 1 MHz and applied reverse voltage of 4 V D.C

²⁾ Thermal resistance from junction to terminal 6.0 mm³ copper pads to each terminal

³⁾ Thermal resistance junction to terminal 6.0 mm³ copper pads to each terminal

SM4001...SM4007

